

國立臺灣師範大學 113 學年度碩士班招生考試試題

科目：電子學

適用系所：電機工程學系

注意：1.本試題共 3 頁，請依序在答案卷上作答，並標明題號，不必抄題。2.答案必須寫在指定作答區內，否則依規定扣分。

1. (10 points) Figure 1 shows an inverting amplifier with an ideal OPA and a current meter. Assume that $R_1 = 3 \text{ k}\Omega$, $R_f = 12 \text{ k}\Omega$, and $R_L = 2 \text{ k}\Omega$.

(a) Find i_m if $v_i = -0.6 \text{ V}$.

(b) Find v_i if $i_m = 2 \text{ mA}$.

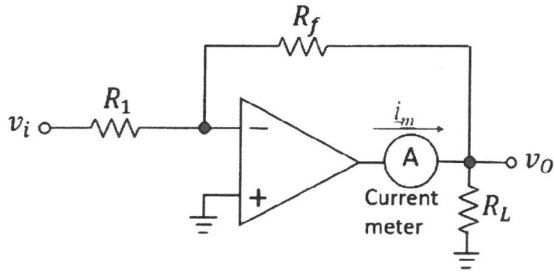


Figure 1

2. (20 points) Figure 2 shows a BJT amplifier. Assume that $V_{CC} = 10 \text{ V}$, $R_{sig} = 20 \text{ k}\Omega$, $R_{B1} = R_{B2} = 100 \text{ k}\Omega$, $R_E = 1 \text{ k}\Omega$, and $R_L = 2 \text{ k}\Omega$. The transistor has $\beta = 100$, $V_{BE} = 0.7 \text{ V}$, and the thermal voltage $V_T = 25 \text{ mV}$. Neglect the effect of r_o . (Note: An infinite capacitance means that the capacitance is large enough to act as a short circuit at all signal frequencies of interest. However, the capacitor still blocks dc.)

(a) Find I_C .

(b) Find R_i , R_o , and v_o/v_{sig} .

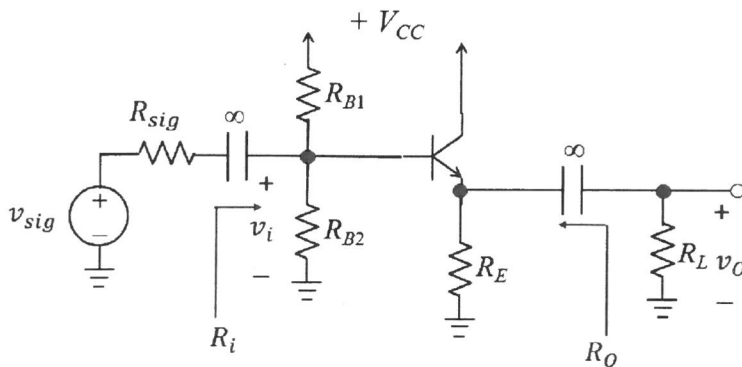


Figure 2

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3. (20 points) Figure 3 shows an NMOS amplifier. Assume that $V_{DD} = V_{SS} = 4\text{ V}$, $R_D = 2\text{ k}\Omega$, and $R_S = 5\text{ k}\Omega$. The NMOS transistor has $V_t = 1\text{ V}$, $\mu_n C_{ox} = 400\text{ }\mu\text{A/V}^2$, $L = 0.2\text{ }\mu\text{m}$, and $W = 2\text{ }\mu\text{m}$. Neglect the effect of r_o . (Note: An infinite capacitance means that the capacitance is large enough to act as a short circuit at all signal frequencies of interest. However, the capacitor still blocks dc.)

- (a) Find I_D and g_m .
- (b) Find R_i , and v_o/v_i .

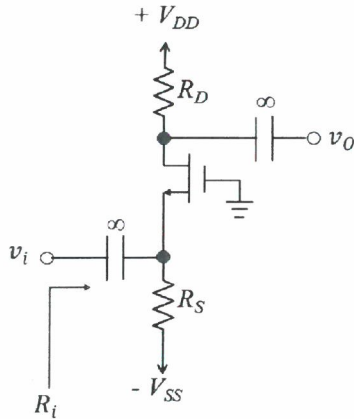


Figure 3

4. (20 points) Figure 4 shows a MOS differential pair. Let $V_{DD} = V_{SS} = 3\text{ V}$, $\mu_n C_{ox} = 400\text{ }\mu\text{A/V}^2$, $L = 0.2\text{ }\mu\text{m}$, $W = 2\text{ }\mu\text{m}$, $V_t = 1\text{ V}$, $I = 1\text{ mA}$, $R_D = 4\text{ k}\Omega$, and neglect the effect of r_o . Assume that the current source I requires a minimum voltage of 1 V to operate properly.

- (a) For $V_{G1} = V_{G2} = -0.2\text{ V}$, find V_S .
- (b) Let $V_{G1} = V_{G2} = V_{CM}$. What is the highest permitted value of V_{CM} ?
- (c) Let $V_{G1} = V_{G2} = V_{CM}$. What is the lowest value allowed for V_{CM} ?
- (d) Let $v_{id} = V_{G1} - V_{G2}$. Find v_o/v_{id} .

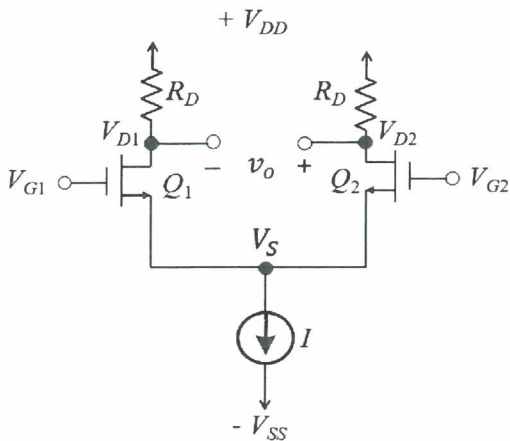


Figure 4

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5. (15 points) Figure 5 shows the equivalent circuit of a voltage amplifier. Assume that $R_{sig} = 30 \text{ k}\Omega$, $R_i = 60 \text{ k}\Omega$, $R_o = 10 \text{ k}\Omega$, $R_L = 90 \text{ k}\Omega$, $A_{vo} = 100 \text{ V/V}$, and $C_i = 0.05 \text{ nF}$.

- Find the amplifier voltage gain V_o/V_{sig} at midband. (i.e. the midband gain A_M)
- Find the upper 3-dB frequency f_H .
- Find $v_o(t)$ for $v_{sig}(t) = 0.1\sin 10^6 t$.

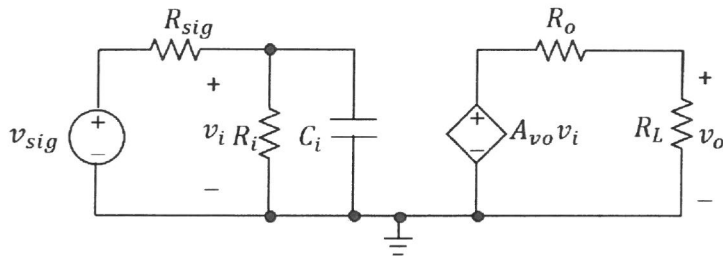


Figure 5

6. (15 points) Figure 6 shows a feedback amplifier. Let $R_{D1} = 5 \text{ k}\Omega$, $R_{D2} = 10 \text{ k}\Omega$, $R_1 = 2 \text{ k}\Omega$, $R_2 = 18 \text{ k}\Omega$, $g_{m1} = g_{m2} = 10 \text{ mA/V}^2$. For simplicity, neglect r_o of each of Q_1 and Q_2 .

- Determine the feedback topology of this amplifier.
- Find the loop gain $A\beta$.
- Find the closed-loop gain v_o/v_{sig} .

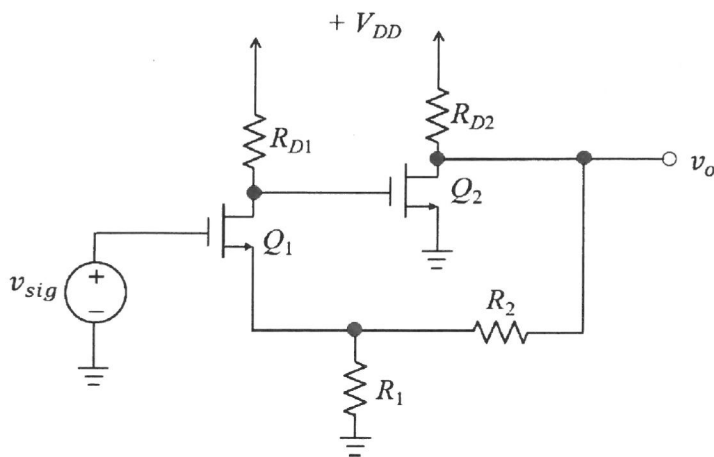


Figure 6